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Abstract

The form ation energy of a soliton was derived in the TLM model to be 2 $_0$ = which is independent of the masses of the polymer atoms. We estimate electronphonon coupling on the soliton form ation energy, particularly, through modications of the harmonic oscillations of (CH) groups. A model based on the amplitude mode form alism is used and the electron-phonon coupling is taken into account to make the electron, a translational mode of the soliton is separately examined, since it corresponds to a zero-energy mode. We get a difference in the form ation energy between the two isotopes of about 0.03eV. Soliton trapping around defects or impurities changes the form ation energy and enlarges the isotope difference.

x1 Introduction

The trans-polyacetylene is an idealm aterial which has excitations such as solitons, polaron, bipolaron, and so on. They can be described very well by the SSH model which was proposed by Su et al.¹⁾ This model contains the electron phonon interaction in addition to electron hopping and lattice vibrations. Takayam a et al.²⁾ m ade the TLM model which is a continuum version of the SSH model. It makes the analytical study of polyacetylene possible.

A number of experimental studies have supported the presence of a kink excitation in t-polyacetylene $(t-(CH)_x)^{3}^{(5)}$ Suzukiet al. have reported an optical absorption measurement in lightly doped polyacetylene.⁵⁾ They have found that the absorption related to the electronic mid-gap state is enhanced by doping. This result has been interpreted as transitions between the mid-gap levels of solitons, induced by the doping, and the conduction band.

In addition to the absorption due to the m id-gap scattering transition, sevral absorptions have been observed near 1370 m⁻¹ and 900 cm⁻¹ in the experiments on the infra-red absorption for a lightly doped (CH)_x.⁷⁾ M ele and R ice have suggested that these peaks are due to lattice vibration.⁸⁾ H orovitz has explained these peaks as the lattice vibration around a soliton added to a dimerized state, proposing a model with several phonon bands. This model is called "the amplitude mode form alism ".⁹⁾

On the other hand, the experim ental studies of the photo-induced absorption spectra of undoped t-(CH)_x have also shown additional infra-red active modes.¹⁰⁾¹¹⁾ The positions are listed in Table I. These infra-red active peaks have been considered to be due to internal vibrationalm odes created by the presence of the soliton. The intensities of these new modes are much weaker than those of the rst three modes.

Ito et al. have studied the phonon structures in the presence of a soliton in the fram ework of the continuum theory for trans-polyacetylene (TLM model). They have analyzed sm all lattice oscillations by using tim e-dependent adiabatic mean-eld equations resulting from a selfconsistent treatment of the electronic eld and the phonon eld.¹²⁾ They have found three localized modes: the Goldstone mode (or the translational mode), the am plitude oscillation mode (the shape mode) and a third mode. Ito et al. have also found that two of the three localized modes, i.e. the Goldstone mode (G M .) and the third localized mode are IR active, whereas the am plitude oscillation mode is inactive.¹³⁾

M ele and H icks have applied H orovitz's am plitude m ode form alism to investigate the optical properties of the localized phonon m odes.¹⁴⁾ T hey have shown that there are three absorption peaks due to the translational m ode in the presence of a single soliton. Terai, O no, and W ada have applied the M ele-H icks theory to calculate the phonon structures, taking account of the translation and the third localized m odes, where they have used three phonon bands.¹⁵⁾ (For each lattice site, there are several degrees of freedom such as bond vibration between C and H and that between nearest neighboring C atom s. W ithin the polym erplane, there are 6 degrees of freedom .¹⁶⁾ T he num ber of IR -active m odes e.g. gerade m odes is, explicitly, 4.) H eeger et al. perform ed an optical-absorption experim ent w ith high resolution, observing two additional IR peaks.¹⁷⁾ Terai et al. have estim ated relative optical absorption intensities and obtained a good agreem ent w ith the experim ent.¹⁸⁾

In this paper, we would like to study an isotope e ect on soliton formation energy in t-polyacetylene. attice oscillations.¹⁹⁾

of the unharm onicity of the e ective potential gives a correction to the phonon frequency and the electron-phonon coupling constant. W e will show that the correction can give the di erence in the form ation energy as large as the observed value.

x2 The e ective potential of the one-dim ensional electron-phonon system

In quasi-one-dimensional electron phonon system bearing the Peierls transition, there are two types of phonon modes. One is the amplitude mode and the other is the phase mode (the CDW sliding mode). In the incom mensurate charge density wave, the ion displacement at the m th site is

 $u_m = u_0 \cos(q_0 m a +)$

where u_0 is the displacement amplitude, q_0 is the wave number which is equal to $2k_F$. The phase variable describes the motion of the charge density wave. In the half-lling case such as trans-polyacetylene, $q_0 = =a$, so that $u_m = ()^m u_0 \cos n$. Thus the dynamics of in t-polyacetylene is written by using only the amplitude of the charge density wave.

Let us consider a one-dimensional electron system including a electron-phonon coupling with a optical phonon eld = gu $_0$ where g is the electron-phonon coupling constant. the H am iltonian is given by

$$H = \frac{1}{2 v_{F} ! Q^{2}} dx [-^{2}(x) + !Q^{2}(x)]$$

$$+ \frac{x}{2} dx [-^{2}(x) + !Q^{2}(x)]$$

$$+ \frac{x}{3} dx [w_{F} : Q^{2}(x) + w_{F} : Q^{2}(x)] (x); \qquad (2.1)$$

where $!_{Q}$ is the bare phonon frequency. The electron eld _s is introduced as a two component spinol eld representing left and right-going waves at the Ferm i level. is a dimensionless electron-phonon coupling constant. the Ham iltonian (2.1) is called the Takayam a-Lin-Liu-M aki (TLM) m odel.²⁾

The coupling between electron and phonon elds induces unharmonicity of the lattice vibration and, due to this non-linearity, the Hamiltonian (2.1) bears a bond order wave state (BOW state).

To investigate the unhamonicity, we make a elective potential for the phonon eld using loop expansion of a partition function.

The partition function of (2.1) is written as follows:

*
$$Z = Z_0 T \exp H_I d$$
 : (2.2)

where hT i being a therm all average with respect to the unperturbed H am iltonian. H_I is the perturbation term given by the electron-phonon coupling y_{1} s. Z₀ is the partition function of the unperturbed H am iltonian in which the electron-phonon coupling is excluded. Z₀ is written in the path integration form,

$$Z_{0} = {}^{Z} (D D {}^{Y}_{S}D {}_{s}) \exp {}^{Z} d (L^{0} + L^{0})$$

$$L^{0} = \frac{1}{2 v_{F} ! {}_{Q}{}^{2}} {}^{Z} dx {}^{"} \frac{0}{0} {}^{!2} + ! {}_{Q}{}^{2} {}^{2} (x)$$

$$L^{0} = {}^{Z} dx {}^{Y}_{s}(x) \frac{0}{0} {}^{s} \frac{(x)}{0} + {}^{X} {}^{Z} dx {}^{Y}_{s}(x) [iv_{F} {}_{3}0_{x}] {}_{s}(x); \qquad (2.3)$$

The therm alaverage in (2.2) is also written by the path integration form. The path integration over $_{\rm S}$ is approximated by a diagram atic calculation. Consider the sum mation over connected loop diagram s which are shown in Fig.1.²⁰⁾²¹⁾ The solid line is associated with the electron G reen function. The solid circle corresponds to the vertex with $_1$ coupling. In the momentum space, the electron G reen function is given by

$$G^{(0)}(!;k)_{s;s^{0}} = \frac{Z Z}{dxd} T_{s}(x;) \frac{Y}{s^{0}}(x^{0}; 0) e^{ikx i!}$$
$$= \frac{i! I + v_{F} k_{3}}{(i!)^{2} (v_{F} k)^{2}}_{s;s^{0}}: \qquad (2.4)$$

where s denotes up or down of the spin orientation. Representing the sum of the diagram s in Fig.1 as U, the partition function is approximately given by

Let us estimate U. The lowest order term with respect to the momentum transfer q between the electron, $_{\rm s}$, and the lattice, (x), is given by the sum mation written as follows:

$$\frac{1}{2} \operatorname{Tr}^{X} \operatorname{dk}^{2} \operatorname{dk}^{1} (0) _{1} \operatorname{G}^{(0)} (\mathbf{i}! \mathbf{k})^{n}$$

$$= \frac{1}{2} \operatorname{dk}^{X} \operatorname{ln}^{Z} (\mathbf{k})^{2} (\mathbf{k})^{2} (\mathbf{k})^{2} \mathbf{k}^{n} \mathbf{k}^{2} \mathbf{k}^$$

where the sum mation over ! is taken over the M atsubara frequency ! = T(2m + 1), m being an integer. (0) is the Fourier transform of (x) at q = 0. Taking zero tem perature lim it and using the relation

$$\frac{1}{2} \sum_{i,j=1}^{X} \ln \frac{i!}{i!} \frac{j_{aj}}{j_{cj}} = \frac{1}{4} \sum_{i=1}^{Z} d'' \tanh \frac{-1}{2} \ln \frac{-1}{2} \frac{j_{aj}}{j_{cj}}$$
$$= \frac{1}{2} (j_{aj} - j_{cj}); \quad (T ! 0): \quad (2.7)$$

we can rewrite (2.6) as

$$\frac{1}{v_{\rm F}}$$
 ² (0) $\ln \frac{(0)}{2}$ $\frac{1}{2}$; (2.8)

where is the electron band cut o given by $= v_F = a$.

The higher order term s with respect to q is given by diagram s shown in Fig.2. The sum mation over these diagram s gives

$$\frac{1}{2} \operatorname{Tr} \sum_{j=1}^{X} \frac{dk}{4} = 1 \frac{\frac{1!}{(1!)^2} + \frac{v_F}{v_F} (k+q) + \frac{1}{2}}{(1!)^2 + \frac{1}{v_F} (k+q)^2 + \frac{1}{2}} = 1 \frac{\frac{1!}{(1!)^2} + \frac{v_F}{v_F} \frac{k}{3} + \frac{1}{1}}{(\frac{1!}{(1!)^2} + \frac{v_F}{v_F} \frac{k}{3} + \frac{1}{2}} = \frac{1}{\frac{1}{v_F}} \frac{\frac{1!}{v_F} + \frac{v_F}{k} \frac{k}{3} + \frac{1}{2}}{\frac{1}{v_F} + \frac{1}{v_F} \frac{2^{\#}}{(v_F + k)^2 - 2}} = \frac{1}{\frac{1}{v_F}} \frac{\frac{1}{v_F} + \frac{v_F}{k} \frac{k}{3} + \frac{1}{2}}{\frac{1}{v_F} + \frac{1}{v_F} \frac{2^{\#}}{(v_F + k)^2 - 2}} = \frac{1}{\frac{1}{v_F}} \frac{\frac{1}{v_F} + \frac{v_F}{k} \frac{k}{3} + \frac{1}{2}}{\frac{1}{v_F} + \frac{1}{2}} = \frac{1}{\frac{1}{v_F}} \frac{\frac{1}{v_F} + \frac{1}{v_F} \frac{k}{(1+v_F)^2}}{\frac{1}{v_F} \frac{k}{2}} = \frac{1}{\frac{1}{v_F}} \frac{1}{(1+v_F)^2} \frac{k}{(1+v_F)^2} \frac{$$

where we subtracted from the rst term in the right hand side of (2.9) the q independent term (the second term). In the real space, this term would be expressed as

$$\frac{1}{v_{\rm F}} ({\rm x}) = \frac{p_{\rm T}}{1+2} \ln \left(+ \frac{q_{\rm T}}{1+2} \right) + \frac{q_{\rm T}}{1+2} ({\rm x})$$
(2.10)

where

$$= \frac{v_{\rm F}}{2 (0)} \dot{\underline{u}}_{\rm QX}^{\rm Q} : \qquad (2.11)$$

(0) is considered to be absolute of the mean value of (x). Since U is expressed by the sum of (2.8) and (2.9), we can study the lattice dynamics of the electron-phonon system (2.1) by using the total electric potential which is given as follows:

$$\frac{1}{2 v_{\rm F}}^{\rm Z} dx \frac{(x)^2}{(x)^2} + 2 (x) \frac{p_{1+2}}{1+2} \ln (+\frac{q_{1+2}}{1+2}) \frac{1}{1} (x) + 2 (x)^2 \ln \frac{j (x)j}{2} (x)^2$$

In the perfectly dimerized state, and in the adiabatic limit, the spatial variance of (x) is equal to zero. The elective potential have double minimum points at = 0 where 0 is determined by

$$_0 = 2 \exp \frac{1}{2}$$
: (2.13)

The potential is written by the dashed line in Fig.3. Thus, we consider that j(0)j which was introduced in (2.10) as the mean value of (x), is given by 0. Therefore, the elective Ham iltonian is given by

$$H = \frac{1}{2 v_{F}} \left[\frac{1}{2} v_{F} \frac{1}{2} \right]_{Q}^{Z} dx - (x)^{2} + \left[\frac{1}{2} (x) \right]_{Q}^{2} + \frac{1}{2} \left[\frac{1}{2} (x) \frac{1}{2} \frac{1}{2} + \frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1}{2} \frac{1}{2} \frac{1}{2} \frac{1}{2} \frac{1}{2} \right]_{Q}^{Z} dx - (x) \frac{1}{2} \left[\frac{1}{2} \frac{1$$

where -(x) is the time-derivative of (x). D and are introduced as follows:

$$D = \frac{p}{1+2} \ln (+1+2) \quad 1; \quad (2.15)$$

$$=$$
 $\frac{0}{2}\frac{0}{0}\frac{1}{0}$; (2.16)

where $_0 = v_F = _0$. As is well-known, the electron-phonon system (2.1) bears the nonlinear excitation. A soliton is the solution of (2.1) which separates $(x) = _0$ phase and $(x) = _0$ phase. The electrice H am iltonian (2.14) also has a soliton solution. It's spatial form is shown in Fig.4. We obtained this form by using the variational method. (Appendix A.) The form of (x) for the soliton is nearly equal to the well-known form.

$$_{\rm s}({\rm x}) = _{0} \tanh {\rm x} = ;$$
 (2.17)

which is the solution of the Hamiltonian (2.1).²⁾ Our result gives a value of the solution width of about = 1.04_0 with $_0 = v_F = _0$.

The soliton excitation energy which is centered around the soliton is mainly kept in the electron system . In a soliton case, the energy level of the electronic states in the valence band are shifted by the lattice distortion and the mid-gap localized state is induced.²⁾ In our model, the property of the electron system is approximated by the electron control dispersion. Since the localized electronic state is not included, our model, (2.14), does not include the exact change of the electronic energy level. U sing (2.17), and using the fact that $_{\rm s}({\rm x})$ is the solution of (A.1), the soliton form ation energy is derived to be $_{0}$ = (Appendix A). Our result gives the di erent value with the result given by the TLM model.^(2.1), in analyzing the lattice dynam ics of polymer chain. A swe will show later, the dispersion relation of phonon and the localized ocillation mode around the soliton obtained in the TLM model are well reproduced in our model. Then, the H am iltonian (2.14) would be suitable for analyzing the parameters , ! $_{0}$, etc.

The eigen mode g_{ν} of the lattice uctuation % f(x)=0 around a static soliton is given by the Schrödinger equation

$$\frac{1}{2 ! \frac{2}{Q}} g_{\gamma} = \frac{p_{1+2}}{\frac{1+2}{2}} \ln \left(+ \frac{q_{1+2}}{1+2} \right) + \frac{q_{\gamma}}{1 + 2} + \ln \frac{j_{s}(x)j}{0} g_{\gamma}; \quad (2.18)$$

where s(x) is the static solution solution of (2.14), i.e. (2.17). In the perfectly dimerized state, the log term of the potential in (2.18) vanishes and the continuum spectral of phonon frequency q is given by

$$\frac{\frac{2}{q}}{2!_{Q}^{2}} = \frac{p \frac{1+s^{2}}{1+s^{2}}}{s} \sinh^{-1}s; \qquad (2.19)$$

where $s = v_F q= (2_0)$, q being the wave num ber of the phonon. Then, the extended m odes of lattice uctuation around the soliton have the spectrum like (2.19). This dispersion relation was also derived by Nakahara and M aki using the random phase approximation (RPA) method for the electron polarization.²²⁾

In the Ham iltonian (2.1), there are localized modes which have non-zero amplitude around the soliton center. They are the Goldstone mode, amplitude oscillation mode and the third localized mode of soliton. These localized modes have been obtained by several groups using the RPA method.^{12);22) 24)} W e show in Appendix B that (2.18) has the zero-energy mode (the Goldstone mode) and that its form is given by $\frac{d_{-s}(x)}{dx}$. Substituting the form of the soliton which is shown in Fig.4 into (2.18), the frequencies of the other localized modes are numerically obtained. (Appendix B) Their frequencies are shown in Table II. O ur result coincides with other works.¹²⁾²³⁾²⁴⁾

In this paper, we discuss the quantum correction to the soliton form ation energy using (2.14) and soliton solution (2.17).

x3 A nharm onicity of the lattice vibration

Because the potential of the lattice eld has the logarithm ic term, the lattice uctuation around = $_0$ has an anharm onic potential. In (2.1), the parameters $!_Q$, and v_F were determ ined so as to obtain good agreements with experimental values of the electron band gap and the phonon dispersion considering the lattice uctuation as the harm onic lattice oscillation. In the dispersion relation (2.19) and the selfconsistency equation for the electron band gap, (2.13), these parameters were used. However, since anharm onicity of the lattice oscillation modi es the mean position of (CH) groups and the energy spectral of phonon dispersion, we should make corrections for the parameters , $!_Q$ and v_F . In the perfectly dimerized case, expanding (x) around = $_0$, the Ham iltonian becomes

$$H \quad ' \quad \frac{1}{2 v_{F}}^{Z} dx \quad \frac{2}{!_{Q}^{2}} + 2 D + 2 ^{2} + \frac{2}{3 _{0}} ^{3} \frac{1}{6 _{0}^{2}} ^{4} \frac{1}{2 v_{F}} dx \quad \frac{2}{0}; \qquad (3.20)$$

where $(x) = _0 + .$ Suppose that the higher order term s in $= _0$ are su ciently small in the quasi-one dimensional system, we neglected term s over 5th order with respect to $= _0$. We compare the potential of (2.14) and (3.20) graphically in Fig.3. The potential of (3.20) is drawn by the solid line. The coincidence is fairly well when $j = _0 j < 0.5$. For the realistic material, t-polyacetylene, the parameters are $0.2, !_0 = 0.38V$, and $_0 = 0.67eV$, then

$$\frac{\frac{2}{2}}{\frac{2}{0}} = T \quad (x; = 0^{+}) \quad (x; 0) = \frac{1}{4 \frac{2}{0}}^{Z} d(v_{\rm F} q) \frac{! \frac{2}{0}}{! q} ' 0:4; \quad (3.21)$$

where $!_q$ is given by (2.19). Considering that over the 5th order contribution from $=_0$ is negligible, we investigate the e ect of lattice uctuation described by (3.20). The bare phonon Ham iltonian which is written by the rst three terms in the right hand side of (3.20) gives the bare G reen function of ,

D (!;k) = T (x;) (x⁰;0) e ^{ikx}e ^{i!}
=
$$\frac{v_F !_Q^2}{(i!)^2 \cdot \frac{2}{k}}$$
; (3.22)

The forth and the fifth terms in the right hand side of (3.20) give 3 point and 4 point vertices, respectively. They are associated with the diagram s in Fig.5.

x4 Correction to the soliton form ation energy

The 3 point and the 4 point vertices give the correction to spectral of the harm onic oscillation. We will make one-loop approximation and estimate the correction to the soliton formation energy. In the one loop approximation, the 3 point vertex gives the elective contribution which is shown by diagram s in Fig.6a).

^Z dx
$$\frac{1}{2} \frac{2}{v_{\rm F} 0} = \frac{1}{2} \frac{1}{v_{\rm F} 0} = \frac{1}{2} \frac{1}{v_{\rm F}} = \frac{1}{2} \frac{1}{v_{\rm F}} \frac{1}{v_$$

In the same way, the 4 point vertex gives the e ective contribution which is shown in Fig.6b). $$\rm Z$$

dx
$$^{2}\frac{1}{2 v_{\rm F}}$$
 m : (4.24)

Here, we introduced the notation $m = \frac{2}{0} = \frac{2}{0}$. Totally, the contribution becomes

,

$$\frac{m}{2 v_{F}}^{2} dx (2_{0} + {}^{2})$$

$$\frac{m}{2 v_{F}}^{2} dx \frac{1}{2} 1 (x)^{2} + 2 (x)^{2} \ln \frac{j (x)j}{2}$$

$$\frac{m}{2 v_{F}}^{2} dx {}^{2}_{0}: \qquad (4.25)$$

Since = $(x)_{0}$ is a small quantity, and since the functional form of the correction term should be similar to the elective potential in (2.18), we approximated the rst line of (4.25) by the second line.

Because the parameters , ! $_Q$, and v_F in (2.1) is selected to give the good coincidence with the realistic material in the mean-eld theory, the H am iltonian should be reconstructed to cancel the contribution (4.25). As the corrected H am iltonian, we obtain

$$H_{R}^{0} = \frac{1}{2 v_{F} !_{Q}^{2}} dx (-(x)^{2} + !_{Q}^{2} !(x))$$

$$\frac{1}{2 v_{F}} dx 2 (x)D (x) + 2 (x)^{2} \ln \frac{j (x)j}{2} !(x)$$

$$+ \frac{m}{2 v_{F}} dx \frac{1}{2} (x) + 2 (x)^{2} \ln \frac{j (x)j}{2} !(x)$$

$$+ \frac{m}{2 v_{F}} dx \frac{1}{2} (x) + 2 (x)^{2} \ln \frac{j (x)j}{2} !(x)$$

$$+ \frac{m}{2 v_{F}} !(x) + (x)^{2} + 2 (x) !(x) !(x) + (x)^{2} + (x)^{2} \ln \frac{j (x)j}{2} !(x)$$

$$+ (x)^{2} + (x)^{2} \ln \frac{j (x)j}{2} !(x)$$

where = $i\frac{\nabla_{\rm F}}{2}\frac{\theta}{\theta \, {\rm g}}$. The third and the forth line in (4.26) is called as the "counter term" which is added to cancel the contribution (4.25). In the derivation of H⁰_R, we assumed that the uctuation = $_0$ is smaller than 1, and terms over the 4th order with respect to = $_0$ is negligible. In the quasione-dimensional electron-phonon system, like polyacetylene, this condition would be satistical. In the purely one-dimensional system, the higher order terms with respect to = $_0$ is not negligible. Then, we can not renormalize the anharm onicity into the form of (4.26). We do not consider the purely one-dimensional case.

Next, we renorm alize the unharm onic contributions which come from the counter terms in (4.26). Repeating these procedures, we obtain the renorm alized H am iltonian which represents the actual situation of the quasi one-dimensional electron-phonon system at the half-lling. By the rede nition of the parameters , v_F and $!_Q$, the renorm alized H am iltonian is written in the form of (2.14). C om paring (2.14) and (4.26), we obtain the renorm alized H am iltonian

$$H_{R} = \frac{1}{2 v_{FRR} |_{QR}^{2}} dx -_{R} (x)^{2} + !_{QR}^{2} |_{R} (x)^{2}$$

$$+\frac{1}{2 v_{FR}}^{Z} dx [2d_{R} (x)D_{R} (x)] + 2 R (x)^{2} ln \frac{j R (x)j}{2 R} \frac{1}{2} : \qquad (4.27)$$

$$\begin{array}{rcl} !_{Q_{R}} &=& (1 & m) \ ^{1=2} (1 + \ln (1 & m)) \ ^{1=2} !_{Q} \\ _{R} &=& (1 + \ln (1 & m)) \ ^{1} \\ _{R} &=& (1 & m) \ ^{1=2} \\ d_{R} &=& (1 & m) \\ v_{F R} &=& v_{F} \\ _{R} &=& v_{F R} = a \end{array}$$

$$(4.28)$$

where a is the lattice constant. We determ ined (4.28) on the condition that v_{FR} and $_{R}$ are invariant under the renorm alization since they are parameters of the electron system. Because m > 0, the corrected parameters $!_{QR}$ and $_{R}$ are larger than the bare values. From $\frac{^{2}}{2} \frac{^{2}}{v_{FR}} = (1 \ m)^{-1} \frac{^{2}}{2} \frac{^{2}}{v_{F}}$, we can see that, in the actualm aterial, the electric potential is $(1 \ m)^{-1}$ times deeper than the uncorrected one.

On the other hand, since the elective potential becomes deeper, the dimensional equation for the soliton is a ected by the renormalization. We calculated the soliton width $_{\rm R}$ for the various values of $1=d_{\rm R}=(1~{\rm m})^{-1}$ using the variational method. (Appendix A) We plot $_{0}=_{\rm R}$ in Fig.7 as the function of $1=d_{\rm R}$. The soliton width becomes narrower as the elective potential becomes deeper. It behaves like

$$\frac{R}{0} = 1.04 d_{R}^{0.12} = 1.04 (1 \text{ m})^{0.12}; \qquad (4.29)$$

in the range $0.2 < d_R^{-1} < 2$.

In the static lim it, = 0, using (A .1), the soliton form ation energy is given by

$$\frac{1}{2 v_{FR}}^{Z} dx \left(\begin{array}{c} 0_{R}^{2} \\ 0_{R} \end{array} \right)^{2} \left(\frac{R}{0} \left(\begin{array}{c} 0_{R}^{2} \\ 0 \end{array} \right)^{2} \right)$$

$$(4.30)$$

where, from the rst to the second line, we used the soliton form $(x) = _0 \tanh(x = _R)$. In addition to (4.30), zero-point lattice oscillation gives a contribution to the total energy, which is explained by the path integration.²¹⁾ The presence of the soliton changes the phonon frequency and this contributes to the soliton form ation energy. Then, the soliton form ation energy is, totally, given by

$$E_{s} = \begin{pmatrix} X \\ 2 \end{pmatrix} + \begin{pmatrix} 1 \\ (1 - m)^{0.88} \end{pmatrix} + \begin{pmatrix} 0 \\ (4.31) \end{pmatrix} + \begin{pmatrix} 0 \\ (4$$

x5 The e ect of im purity

In the realistic material, there are lattice defects or impurities. The potential due to the impurities traps the soliton and therefore the formation energy is a ected by the trapping energy. Suppose spin or charge of the soliton interacts with impurity and the impurity potential is given by the delta function V(x). If the soliton is rigid, the trapping energy will be Z

$$V dx (x)n (x X)' V \frac{n_0}{\cosh^2 X}$$
; (5.32)

where X is the position of soliton center, V the magnitude of the impurity potential, is the soliton width, and n (x) is the charge or spin density of the soliton. We approximated n (x) as $n_0 = \cosh^2 (x=)$ because the electron density in the mid-gap state of the soliton has this form .²⁾ Since we are interested in the dynamics of the soliton center and the elect of soliton trapping. We use the electric H amiltonian.

$$H_{tr} = \frac{P^2}{2M} - \frac{U}{\cosh^2 X};$$
 (5.33)

with $U = y_{n_0} j$. Here M is the soliton mass which is given by

$$M = \frac{1}{2 v_{\rm F}}^{\rm Z} dx - \frac{1}{0} \frac{d(x)}{dx}^{\rm 2}; \qquad (5.34)$$

and P is the momentum conjugate to the position of the soliton center X . (5.33) gives the trapping energy spectrum given as follows:

$$E_{n} = \frac{1}{8M^{2}} \left(\frac{q}{1 + 8M U^{2}} - (2n + 1) \right)^{2}; \quad (5.35)$$

where n being the non-negative integer which satis es 0 n ($\frac{p}{1+8M U^2}$ 1)=2. The experimental value of the soliton formation energy would correspond to the sum of "pure" formation energy of the soliton E_s and the trapping energy E₀. The formation energy of the soliton is lowered by

$$E_{0} = \frac{1}{8M^{2}} \left[\frac{q}{1+8M U^{2}} \right]^{2} (5.36)$$

In the weak trapping lim it, M U $^2 << 1$, E $_0$ becomes 2M U 2 2 . When M U $^2 >> 1$, E $_0$ becomes U + $^{\text{P}}$ $\overline{\text{U}=(2M^{-2})}$.

x6 Isotope e ect

The realistic t-polyacetylene has several norm alm odes of lattice oscillations. Horovitz has proposed the model which include these norm alm odes introducing plural components of phonon elds.

The multim ode Hamiltonian is given by ²⁵⁾

where 3 types of phonon elds are taken into account, $!_0$ being the renormalized phonon frequency

$$!_0^2 = 2 !_Q^2$$
:

(x) is de ned by

$$(x) = (x)^{1=2} (x)^{1=2$$

where is the coupling constant of the th phonon with the bare frequency ! . There is a relation $$_{\rm X}$$

U sing (6.37), the elective potential is obtained as in the same way as shown in the section 2. Introducing a phonon eld of the th normalmode by , is expanded around (x) as follow s:

$$= (x) + ; = X - \frac{!}{!_0} :$$
 (6.40)

Substituting (6.40) into the e ective Ham iltonian (2.14), we obtain

$$H = \frac{1}{2 v_{F}} \sum_{v_{F}}^{Z} (x) dx + \frac{1}{2 v_{F}} \sum_{v_{F}}^{X} dx [2 + 1^{2} 2] + \frac{1}{v_{F}} \sum_{i}^{X} dx \frac{p_{F}}{2} - \frac{1}{2 v_{F}} \frac{1}{2 v_{F}} D + \frac{1}{v_{F}} \sum_{i}^{X} dx \frac{p_{F}}{2} - \frac{1}{2 v_{F}} \frac{1}{2 v_{F}} \frac{p_{F}}{2 v_{F}} \frac{1}{2 v_{F}} \frac{p_{F}}{2 v_{F}} \frac{1}{2 v_{F}} \frac{p_{F}}{2 v_{F}} \frac{1}{2 v_{F}$$

where D is given by (2.15). The eigen m ode of the H am iltonian is constructed as follows. From (6.41), the Schrödinger equation of an eigen m ode ' is given by

$$' = !^{2}' + 2^{X} - !! D'$$

$$+ 2^{X} - !! D'$$

$$+ 2^{X} + 2^{X} + 1 + \ln \frac{j(x)j}{0} - \frac{1}{2}' : (6.42)$$

Since we are considering the one-dimensional case, the eigen-m ode function of (6.42) can be expressed by the superposition of g_{γ}

$$' = {}^{X} C ; g;$$
 (6.43)

where g_{\cdot} is the eigen function of (2.18). We write the frequency of g_{\cdot} by \cdot . Substituting (6.43) into (6.42), and using eq.(2.18), C ; \cdot is given by the equation,

$$\begin{array}{c} s \\ c \\ c \\ c \\ \end{array} \\ \cdot \\ \end{array} \\ \begin{array}{c} 2 \\ - 1 \\ 1 \\ \frac{2}{1^2} \\ \end{array} \\ \begin{array}{c} 2 \\ - 1 \\ \frac{2}{1^2} \\ \frac{2}$$

This equation was obtained in a di erent way using the RPA method by Terai et al.¹⁵⁾ From (6.44), the expansion coe cient C ; and the frequency is obtained. is given by the solution of the equation

$$1 \quad \frac{!_{Q}^{2}}{!_{Q}^{2}} = D();$$

$$D() = \frac{X}{-\frac{!^{2}}{2}!^{2}} \quad (6.45)$$

There are three solutions for each '. Let us call them as ; (= 1;2;3). Using (6.44) and (6.45), C ; is given by

$$C_{i} = \frac{!}{!^{2} - \frac{2}{i}} - \frac{1}{(!^{2} - \frac{2}{i})^{2}} - \frac{!^{2}}{(!^{2} - \frac{2}{i})^{2}} - \frac{!^{2}}{(!^{2} - \frac{2}{i})^{2}} - C_{i} + C_$$

U sing (6.43), (6.45) and (6.46), the phonon frequency and the eigen-m ode function are obtained.

Substituting the values in Table II into (6.45), the localized modes around a soliton are obtained. They are summarized in Table I for isotopes of $(CH)_x$ and $(CD)_x$. The experimental results are also shown. In the calculation of the phonon frequency, we used the parameters and ! shown in Table III. They were determined by Vardeny et al. from the Raman scattering experiment. The phonon frequencies in $(CH)_x$ are relatively larger than those in $(CD)_x$.

Let us compare the formation energy of the soliton between the two isotopes of tpolyacetylene. As we have discussed in x3, the renormalized Ham iltonian is constructed by adding the counter term, and the soliton formation energy should be corrected by the uctuation $m = {}^2 = {}^2_0$. Using the dispersion relation ${}_{jk}$ which is obtained from (6.45) for the dimerized state, and using the phonon G reen function which is derived from (6.41), m is estimated as follows:

$$m = \bigvee_{\substack{(1) \\ ($$

In the calculation in (6.47), we used $_{FI}$ which is given by (2.19). In Appendix B, we have solved (2.18) for the soliton approximately. Since we have made an expansion of D up to 6th order with respect to , we cannot exactly reproduce the dispersion relation (2.19). Then, we will use the phonon frequencies given by the RPA m ethod which is explained in ref.[12]. Substituting the phonon frequencies and (6.47) into (4.31), the correction to the soliton form ation energy is totally given by

$$E_{s} = \begin{pmatrix} 0.0323 \text{eV}; & \text{for (CH)}_{x} \\ 0.0033 \text{eV}; & \text{for (CD)}_{x} \end{pmatrix}$$
(6.48)

On the assumption that the di erence in the electron band gap $_0$ between the two isotopes is very small, the corrected parameters are obtained by (4.28) where the parameters = 0.2 and $_0 = 0.656$ eV are used for both isotopes. The corrected coupling constant $_R$ for (CH)_x becomes larger than that for (CD)_x. Then, the soliton formation energy in (CH)_x becomes about 0.029eV larger than that in (CD)_x.

The isotope di erence of the soliton form ation energy is observed by the photo-induced absorption experiment by Schaeretal.¹⁷⁾¹⁹⁾ They concluded that, from the observed value, the dierence is about 0.03eV 0.04eV. This is of the same order with our theoretical estimation. However, the experimental result is a bit larger than ours by about 0.01eV. This dierence would come from the trapping by in purities. In the optical absorption experiment, the frequency of T_1 mode, which corresponds to the excitation of soliton translational motion in (CH)_x is larger than in (CD)_x. This dierence is considered to come from the soliton mass M_s. In the multi-component theory (the amplitude mode form alism), the soliton mass is given by ²⁶

$$M_{s} = \frac{1}{v_{F}} X_{F} \frac{Z}{!^{2}} dx \frac{d_{s}(x)}{dx}^{2} = \frac{4u_{0}^{2}X}{a} \frac{K}{K} M^{1} dx \frac{1}{0} \frac{d_{s}(x)}{dx}^{2}$$
(6.49)

where M is the elective mass of the the lattice oscillation mode and K is the elective spring constant of the them ode. They are introduced by the following relation.

Since the bonds between atoms get small in uncess from the hydrogen mass, the isotope di erence of K would be small. On the other hand, the elective mass of lattice oscillation in $(CH)_x$ is smaller than that in $(CD)_x$. Therefore, from (6.49), the soliton mass in $(CH)_x$ is smaller than in $(CD)_x$. Thus, in su ciently deep in purity potential, from (5.36), the trapping energy in $(CD)_x$ is lower than $(CH)_x$, and the excitation energy from the lowest bound state to higher excited state in $(CH)_x$ is larger than that in $(CD)_x$. In x5 we saw that the soliton form ation energy is a lected by the soliton trapping energy. Suppose that the impurity potential is su ciently deep and that the potential is well-approxim ated

by the harm onic potential at the bottom . Considering the soliton trapping energy as the energy of the zero-point oscillation around the in purity potential, the isotope di erence of the trapping energy is about $(0.062 \quad 0.0507)=2 = 0.006eV$, where the experim ental data of T₁ m ode which is shown in Table I is used. Therefore, the soliton form ation energy in (C H)_x is larger than that in (C D)_x by 0.0029 + 0.006 = 0.035eV. This theoretical estim ate agrees well with the observed value.

x7 Sum m ary

We investigated the e ect of lattice uctuation on a soliton and compared our result with experimental result observed by the photo-induced optical absorption experiment. First, we renormalized the electron-phonon interaction into the electron solution of lattice distortion eld. Then, the electron of the lattice uctuation around the soliton solution. We obtained the dispersion relation of the lattice uctuation around the soliton using the electron tive potential and reproduced the theoretical result given by using the RPA method. There is a good agreement between our result and experimental result about the level position of the localized mode around the soliton.

Due to the anham onicity of lattice vibration, the phonon frequency and the electron band gap in the actual potential is a ected from the mean-eld value. We proposed the renormalized Hamiltonian (4.27) and estimated the correction to the soliton formation energy. The magnitude of the correction is estimated by the one-loop renormalization $m = {}^2 = {}^2_0$ where is the lattice uctuation eld and ${}_0$ is the observed value of the electron band gap. We found that the actual depth of the double-well potential is wider than the depth expected by the mean-eld theory. The correction to the formation energy due to the electron-phonon coupling is given by

$$E_{s} = \frac{X}{2} + \frac{1}{2} + \frac{X}{12} + \frac{1}{2} + \frac{1}{$$

On the assumption that there are di erences in the electron-phonon coupling constant and the phonon frequency between the two isotopes, we found that the form ation energy in $(CH)_x$ is larger than that in $(CD)_x$ by about 0.029eV. In the realistic material, the soliton form ation energy would be a ected by the soliton trapping by the impurities. We have shown that the isotope di erence of the soliton form ation energy is widened by the trapping energy. In the experimental result, the di erence between the two isotopes is about 0.03eV

0:04eV. The di erence from our result is of the same order with the trapping energy. This suggests the relevance of further theoretical and experimental investigation of the soliton dynamics.

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A. Soliton solution

The Ham iltonian (2.14) has a kink solution (soliton) connecting the two m in imum points $= _0$. Let us calculate a static soliton using (2.14). The Lagrange equation of (2.14) in the static limit is given by

$$2 \frac{p \frac{1}{1+2}}{2} \ln(1+q \frac{1}{1+2}) + 2 \ln \frac{j j}{2} + - = 0; \quad (A.1)$$

where = $i\frac{0}{2}\frac{0}{0}$. 0 is given by $0 = v_F = 0$. Using (2.13) and introducing the notation u = 0, (A.1) is rewritten as follows:

$$\frac{1}{6} \int_{0}^{2} \frac{d^{2}u}{dx^{2}} = 2u \ln j_{1} j_{2}$$
 (A 2)

Here we expanded the left hand side of (A, 1) up to the second order with respect to $\$. The solution is obtained under the condition

$$u(x) = 1; at(x ! 1);$$

 $u(0) = 0;$ (A.3)

Multiplying $\frac{du}{dx}$ to (A 2), and making an integration over x, (A 2) becomes

$$\frac{1}{p-\frac{1}{6}} \int_{0}^{Z} \int_{0}^{x_{0}} \frac{\frac{e_{u}}{e_{x}}}{1+u^{2}(2\ln j_{1}j-1)} dx = \int_{0}^{Z} \int_{0}^{x_{0}} dx$$
 (A.4)

From (A.4), the soliton is given by

$$(x) = {}_{0}u = {}_{0}g^{1} \frac{p}{6} \frac{x}{0};$$

$$g(u) = {}_{0}^{Z} \frac{u}{1 + u^{2}(2 \ln j_{1}j - 1)}:$$
(A.5)

The dotted line in Fig. 4 shows (x) given by (A.5). It is nearly equal to $_0 \tanh (2.2x) = _0$.

(A 5) is narrower than $\tanh x = 0$. However, considering the higher order derivatives in (A 1) and using the variational method, it is shown that the soliton width becomes wider and its form is similar to the form $\tanh (x = 0)$. Since the function (A 5) would be well approximated by sgn(z) $_0$ (1 exp(3:88jzj))(1 0:497 exp(3:88jzj)), where z = x = 0, we use the trial function

$$s(x) = sgn(z)_{0} (1 exp(ajz))(1 0.497 exp(ajz));$$
 (A.6)

where a is a real number. Substituting (A.6) into (2.14) and taking the static limit, the mean value of (2.14) is larger than the dimerized state by

$$\frac{0}{a} \quad \text{Re 1249} \quad \frac{p}{\frac{4}{a}a^2} \sin^{-1}\frac{a}{2} \quad 1 \quad + \ 0.1245 \quad \frac{p}{\frac{1}{a}a^2} \sin^{-1}a \quad 1 \quad + \ 0.9452 ;$$
(A.7)

where we have om itted the imaginary part of the mean value. We used the following relation. Z

(x)
$$\frac{\theta^{2n}}{\theta^{2n}z}$$
 (x)dz = 2a^{2n 1} [0:6305 + 0:12351(2)^{2n 1}]: (A.8)

(A.7) has a minimum point at a = 1:70. Then, (A.6) is 2:28 times wider than the function (A.5). Solid line in Fig.4 shows (A.6) with a = 1:70. Its form is nearly equal to the form of

$$_{s}(x) = _{0} \tanh(x =);$$
 (A.9)

with

$$= 1:04_{0}:$$
 (A.10)

U sing that (x) is the solution of (A.1), the soliton form ation energy is given by

$$\frac{1}{2 v_{\rm F}}^{\rm Z} dx ({}_{0}^{2} {}_{\rm s}^{2} (x)):$$
 (A.11)

Since the soliton form (A.9) has the same form as the solution of the original H am iltonian (2.1), it is adequate to use $_{s}(x) = _{0} \tanh(x = _{0})$ for the estimation of (A.11). Therefore, (A.11) becomes $_{0} = .$

The correction due to the renorm alization of the unharm onic potential gives the elective Hamiltonian (4.26). When d_R is varied, the soliton width $_R$, which is obtained by using the trial function (A.6), changes. We plotted $_R$ for various values of d_R ¹ in Fig.7.

B. Lattice uctuation around a soliton

D i erentiating (A.1) with respect to x = 0 = x, we obtain the following equation.

T

$$\frac{p}{1+2} \ln(1+\frac{q}{1+2}) = 1 \frac{d_{s}(x)}{d(x)} + 1 + \ln \frac{j_{s}(x)j}{j_{0}j} \frac{d_{s}(x)}{d(x)} = 0; \quad (B.1)$$

C om paring (B.1) with (2.18), we nd that $\frac{d}{d(x)}$ is an eigen mode with zero energy, i.e. the G oldstone mode.

In the calculation of the other eigen m ode around the soliton, we use the soliton form obtained in Appendix A. The eigen-m ode equation (2.14) is approximated by

$$\frac{1}{2! {}_{0}^{2}} g_{1} = \frac{1}{12} \frac{g^{2}}{g(x)^{2}} + \frac{1}{120} \frac{g^{4}}{g(x)^{4}} + \frac{1}{840} \frac{g^{6}}{g(x)^{6}} g_{1} + \frac{1}{1 + \ln \frac{j(x)j}{g}} g_{1} : (B 2)$$

I.

where we expanded D until 6th derivatives with respect to $x \cdot U \sin q$ (A.6) with a = 1:70, the eigen mode is determined by the numerical diagonalization. There are two additional modes with localized character. The eigen values of the localized modes are summarized in Table I. They have a good coincidence with the result given by ref.[23].

Figure Captions

- Fig. 1: The loop diagrams which contribute to the elective potential of the lattice distortion. These diagrams do not have the momentum transfer between the electron and the lattice.
- Fig. 2: The loop diagrams which contribute to the electric potential of the lattice distortion. These diagrams have the momentum transfer q between the electron and the lattice.
- Fig. 3: The dependence of the elective potential. The dotted line is the elective potential which is given by the H am iltonian (2.14). The solid line is the potential (3.20)
- Fig. 4: The soliton conguration. The dotted line is the solution of the soliton equation which is approximated by the second order dimential equation (A 2). The solid line is the soliton which is given by the variational method. This form is nearly equal to the form $\tanh(x = R)$.
- Fig. 5: The diagram s of the 3 point and 4 point vertices which appear in the H am iltonian (3.20).
- Fig. 6: The one loop renorm alization diagram s for the 3 point vertex and 4 point vertex, respectively.
- Fig. 7: The d_R^{-1} dependence of soliton width. The soliton is obtained by the variational method using the renormalized Hamiltonian (4.27), where the trial function is chosen to be (A.6). Since the function (A.6) has the form nearly equal to tanh (0:567ax= $_0$), the soliton width $_R$ is given by $_R = _0 = (0.567a)$.

Table I: The frequencies of the localized m odes around the soliton. The T m odes correspond to the translational m ode of soliton and the B m odes com e from the third localized m ode around the soliton.

Table II : W e sum m arized the values of $!^2 = (2 !_Q^2)$ for the localized m odes of the lattice uctuations around the soliton. They are obtained by the num erical diagonalization of (2.14) which is approximated by the dimension (B.2).

Table III : The bare values of the phonon frequencies and the electron-phonon coupling constants. These values were used in the analysis of the Ram an scattering experiment of t-polyacetylene by Vardeny et. al^{3}

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	T heory ¹⁾		P resent	Result	Experiment		
	(CH) _x	(CD) _x	(CH) _x	(CD) _x	(CH) _x	(CD) _x	
T ₁ (! ₀₀)	488	410	0.	0.	500	400	
T ₂ (! ₁₀)	1278	1045	1270	1014	1280	1045	
T ₃ (! ₂₀)	1364	1216	1344	1207	1365	1224	
B ₁ (! ₀₂)	1049	850	1079	862	1035	835	
B ₂ (! ₁₂)	1292	1193	1293	1197	-	-	
B ₃ (! ₂₂)	1445	1333	1463	1368	1440	1300	

	Goldstone mode	Amplitude oscillation mode	Third localized mode
$!^{2} = (2 !_{Q}^{2})$	0.00	0.7186	0.9593

	(CH) _x			(CD) _x				
	=	!	(cm	1)	=	!	(cm	1)
= 1	0.07		1234		0.06		921	
= 2	0.02		1309		0.005		1207	
= 3	0.91		2040		0.93		2040	